MOTOROLA SEMICONDUCTOR TECHNICAL DATA

Product Preview

Low-Voltage CMOS Octal Transceiver

With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX2245 is a high performance, non-inverting octal transceiver operating from a 2.7 to 3.6V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A VI specification of 5.5V allows MC74LCX2245 inputs to be safely driven from 5V devices. The MC74LCX2245 is designed to reduce output overshoot and undershoot and is suitable for memory address driving and all TTL level bus oriented transceiver applications; especially those requiring the very quiet outputs.

Current drive capability is 12mA at both A and B ports. The Transmit/Receive (T/R) input determines the direction of data flow through the bi-directional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

- Designed for 2.7 to 3.6V VCC Operation
- 5V Tolerant Interface Capability With 5V TTL Logic
- · Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When V_{CC} = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 12mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10μA)
 Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

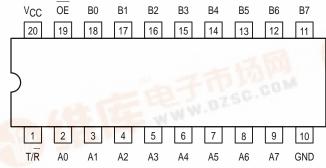


Figure 1. 20-Lead Pinout (Top View)

MC74LCX2245



LOW-VOLTAGE CMOS OCTAL TRANSCEIVER



DW SUFFIX 20-LEAD PLASTIC SOIC CASE 751D-04



M SUFFIX 0-LEAD PLASTIC SOIC EIAJ CASE 967-01



SD SUFFIX 20-LEADPLASTIC SSOP CASE 940C-03



DT SUFFIX 20-LEAD PLASTIC TSSOP CASE 948E-02

PIN NAMES

Pins	Function
OE_ T/R A0–A7	Output Enable Input Transmit/Receive Input Side A 3-State Inputs or 3-State Outputs
B0-B7	Side B 3–State Inputs or 3–State Outputs

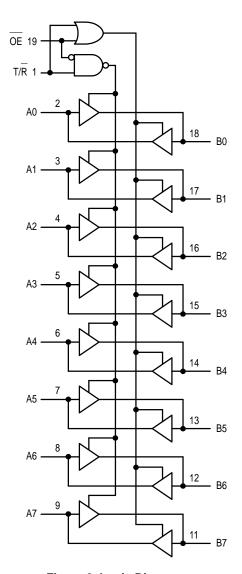


Figure 2. Logic Diagram

INP	UTS	OPERATING MODE		
OE	T/R	Non–Inverting		
L	L	B Data to A Bus		
L	Н	A Data to B Bus		
Н	X	Z		

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions are Acceptable; For ICC reasons, Do Not Float Inputs

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
VCC	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \le V_{I} \le +7.0$		V
VO	DC Output Voltage	$-0.5 \le V_{O} \le +7.0$	Output in 3–State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Note 1.	V
lık	DC Input Diode Current	– 50	V _I < GND	mA
lok	DC Output Diode Current	– 50	V _O < GND	mA
		+50	AO > ACC	mA
Io	DC Output Source/Sink Current	±50		mA
Icc	DC Supply Current Per Supply Pin	±100		mA
I _{GND}	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

^{*} Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute—maximum—rated conditions is not implied.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Unit
Vcc	Supply Voltage Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
VI	Input Voltage	0		5.5	V
Vo	Output Voltage (HIGH or LOW State) (3–State)	0 0		VCC 5.5	V
^I ОН	HIGH Level Output Current, V _{CC} = 3.0V – 3.6V			-12	mA
loL	LOW Level Output Current, V _{CC} = 3.0V – 3.6V			12	mA
^I ОН	HIGH Level Output Current, V _{CC} = 2.7V – 3.0V			-8	mA
loL	LOW Level Output Current, V _{CC} = 2.7V - 3.0V			8	mA
TA	Operating Free–Air Temperature	-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, V _{IN} from 0.8V to 2.0V, V _{CC} = 3.0V	0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			T _A = -40°C	T _A = -40°C to +85°C	
Symbol	Characteristic	Condition	Min	Max	Unit
VIH	HIGH Level Input Voltage (Note 2.)	2.7V ≤ V _{CC} ≤ 3.6V	2.0		V
V _{IL}	LOW Level Input Voltage (Note 2.)	2.7V ≤ V _{CC} ≤ 3.6V		0.8	V
Vон	HIGH Level Output Voltage	$2.7V \le V_{CC} \le 3.6V; I_{OH} = -100\mu A$	V _{CC} - 0.2		V
		$V_{CC} = 2.7V; I_{OH} = -4mA$	2.2		
		$V_{CC} = 2.7V; I_{OH} = -8mA$	2.0		1
		V _{CC} = 3.0V; I _{OH} = -6mA	2.4		1
		$V_{CC} = 3.0V; I_{OH} = -12mA$	2.0		

^{2.} These values of $V_{\mbox{\scriptsize I}}$ are used to test DC electrical characteristics only.

^{1.} Output in HIGH or LOW State. IO absolute maximum rating must be observed.

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DC ELECTRICAL CHARACTERISTICS (continued)

			T _A = -40°C	to +85°C	
Symbol	Characteristic	Condition	Min	Max	Unit
VOL	LOW Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$; $I_{OL} = 100\mu A$		0.2	V
		$V_{CC} = 2.7V; I_{OL} = 4mA$		0.4	
		V _{CC} = 2.7V; I _{OL} = 8mA		0.6	
		$V_{CC} = 3.0V; I_{OL} = 6mA$		0.55	
		$V_{CC} = 3.0V; I_{OL} = 12mA$		0.8	
lj	Input Leakage Current	$2.7V \le V_{CC} \le 3.6V; \ 0V \le V_{I} \le 5.5V$		±5.0	μΑ
loz	3-State Output Current	$2.7 \le V_{CC} \le 3.6V$; $0V \le V_{O} \le 5.5V$; $V_{I} = V_{IH}$ or V_{IL}		±5.0	μΑ
lOFF	Power-Off Leakage Current	$V_{CC} = 0V$; V_I or $V_O = 5.5V$		10	μΑ
ICC	Quiescent Supply Current	$2.7 \le V_{CC} \le 3.6V$; $V_I = GND$ or V_{CC}		10	μΑ
		$2.7 \le V_{CC} \le 3.6V$; $3.6 \le V_I$ or $V_O \le 5.5V$		±10	μΑ
ΔlCC	Increase in I _{CC} per Input	$2.7 \le V_{CC} \le 3.6V; V_{IH} = V_{CC} - 0.6V$		500	μΑ

AC CHARACTERISTICS (Note 3., $t_R = t_F = 2.5 \text{ns}$; $C_L = 50 \text{pF}$; $R_L = 500 \Omega$)

				Limits		
			T _A = -40°C to +85°C		1	
			V _{CC} = 3.0	OV to 3.6V	V _{CC} = 2.7V]
Symbol	Parameter	Waveform	Min	Max	Max	Unit
tPLH tPHL	Propagation Delay Input to Output	1	1.5 1.5	10.0 10.0	11.0 11.0	ns
^t PZH ^t PZL	Output Enable Time to High and Low Level	2	1.5 1.5	11.5 11.5	12.5 12.5	ns
tPHZ tPLZ	Output Disable Time From High and Low Level	2	1.5 1.5	7.5 7.5	8.5 8.5	ns
^t OSHL ^t OSLH	Output-to-Output Skew (Note 4.)			1.0 1.0		ns

^{3.} These AC parameters are preliminary and may be modified prior to release.

DYNAMIC SWITCHING CHARACTERISTICS

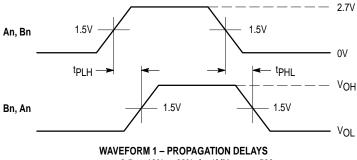
			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
VOLP	Dynamic LOW Peak Voltage (Note 5.)	$V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$		0.8		V
V _{OLV}	Dynamic LOW Valley Voltage (Note 5.)	$V_{CC} = 3.3V$, $C_L = 50pF$, $V_{IH} = 3.3V$, $V_{IL} = 0V$		0.8		V

^{5.} Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

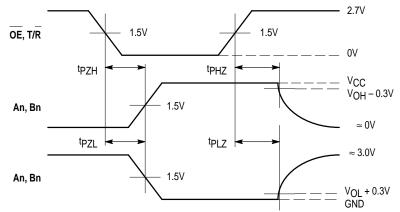
^{4.} Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (tOSHL) or LOW-to-HIGH (tOSLH); parameter guaranteed by design.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Parameter Condition		Unit
C _{IN}	Input Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10MHz, V_{CC} = 3.3V, V_{I} = 0V or V_{CC}	25	pF

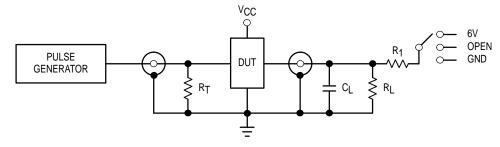


 t_R = t_F = 2.5ns, 10% to 90%; f = 1MHz; t_W = 500ns



WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES $t_R = t_F = 2.5 ns,\, 10\%$ to $90\%;\, f = 1 MHz;\, t_W = 500 ns$

Figure 3. AC Waveforms

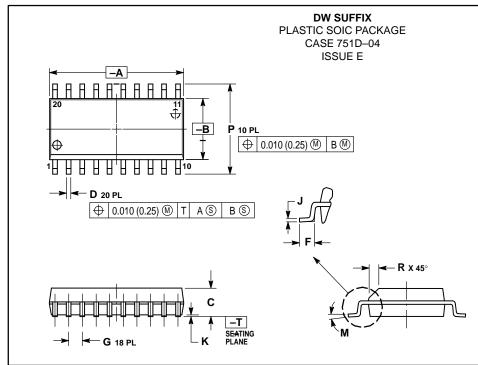


TEST	SWITCH
tPLH, tPHL	Open
tPZL, tPLZ	6V
Open Collector/Drain tpLH and tpHL	6V
tpzh, tpHz	GND

 C_L = 50pF or equivalent (Includes jig and probe capacitance) R_L = R_1 = 500 Ω or equivalent R_T = Z_{OUT} of pulse generator (typically 50 Ω)

Figure 4. Test Circuit

OUTLINE DIMENSIONS



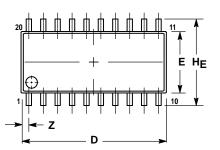
NOTES:

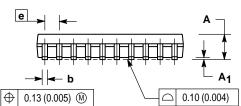
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.150
- (0.006) PER SIDE.

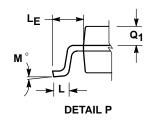
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

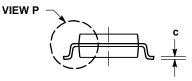
	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	12.65	12.95	0.499	0.510
В	7.40	7.60	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27	BSC	0.050	BSC
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
М	0°	7°	0°	7°
Р	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

M SUFFIX PLASTIC SOIC EIAJ PACKAGE CASE 967-01 ISSUE O









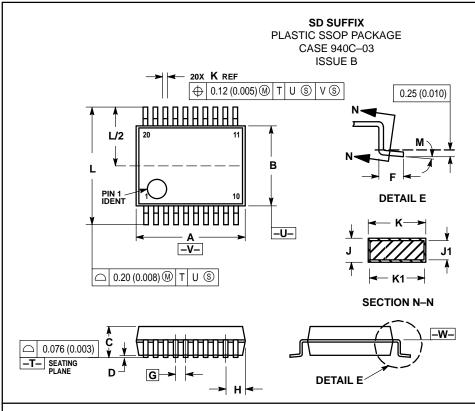
NOTES:

- 1 DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD
 FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 4 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 5 THE LEAD WIDTH DIMENSION (b) DOES NOT
- INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
Α ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.18	0.27	0.007	0.011
D	12.35	12.80	0.486	0.504
Е	5.10	5.45	0.201	0.215
е	1.27	BSC	0.050	BSC
ΗE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
ᄺ	1.10	1.50	0.043	0.059
М	0 °	10°	0 °	10°
Q ₁	0.70	0.90	0.028	0.035
Z		0.81		0.032

OUTLINE DIMENSIONS

DT SUFFIX

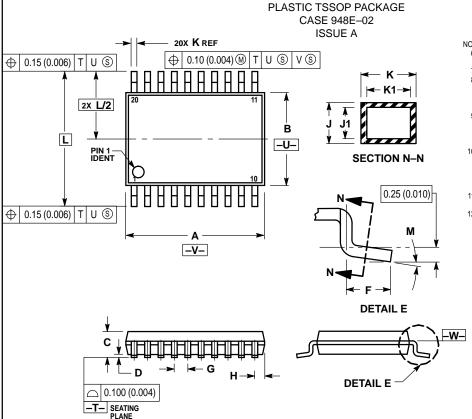


- NOTES.

 13 DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M, 1982.
 14 CONTROLLING DIMENSION: MILLIMETER.
 15 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15
- (0.006) PER SIDE.

 16 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.15 (0.006)
- 17 DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION/INTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF K DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR INTRUSION SHALL NOT REDUCE DIMENSION K BY MORE THAN 0.07 (0.002) AT LEAST MATERIAL CONDITION.
- 18 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 19 DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIMETERS		INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	7.07	7.33	0.278	0.288		
В	5.20	5.38	0.205	0.212		
С	1.73	1.99	0.068	0.078		
D	0.05	0.21	0.002	0.008		
F	0.63	0.95	0.024	0.037		
G	0.65 BSC		0.026 BSC			
Н	0.59	0.75	0.023	0.030		
۲	0.09	0.20	0.003	0.008		
J1	0.09	0.16	0.003	0.006		
K	0.25	0.38	0.010	0.015		
K1	0.25	0.33	0.010	0.013		
L	7.65	7.90	0.301	0.311		
M	0 °	8°	0 °	8°		



NOTES:

- 6 DIMENSIONING AND TOLERANCING PER ANSI
- 714.5M, 1982.
 7 CONTROLLING DIMENSION: MILLIMETER.
 8 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- 9 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
- 10 DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 11 TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.
- 12 DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	6.40	6.60	0.252	0.260
В	4.30	4.50	0.169	0.177
С	-	1.20	_	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
Н	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
М	0°	8°	0°	8°

MC74LCX2245

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